## SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 4097, REV. A

# POWER SCHOTTKY RECTIFIER Low Reverse Leakage

### Applications:

Switching Power Supply · Converters · Free-Wheeling Diodes · Polarity Protection Diode

#### Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	200	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form Common Cathode (N)/Common Anode(P)	150	A
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form Doubler (D)	120	A
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave (per leg)	1650	A
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	$T_J = 25 \ ^{\circ}C, I_{AS} = 1.3 \text{ A},$ L = 40mH (per leg)	27	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 µs f limited by T <sub>J</sub> max V <sub>A</sub> =1.5V <sub>R</sub>	1.3	A
Thermal Resistance	R <sub>thJC</sub>	Per Package	0.2	°C/W
Max. Junction Temperature	TJ	-	-65 to +175	O°
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +175	°C

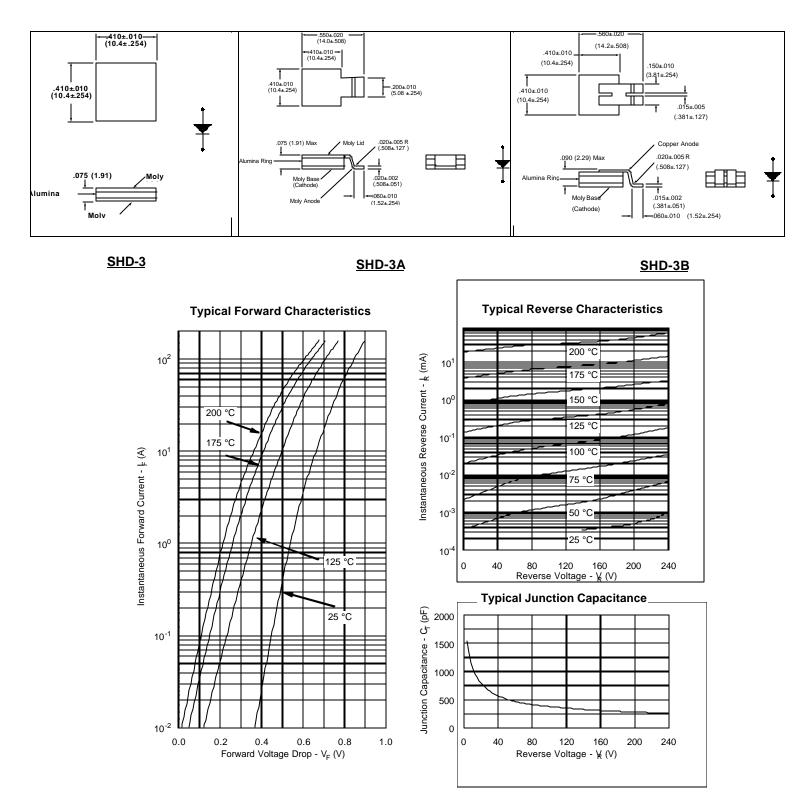
### **Electrical Characteristics:**

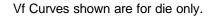
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.95	V
		(per leg) measured at the leads		
	V <sub>F2</sub>	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.79	V
		(per leg) measured at the leads		
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 200V, Pulse,	0.6	mA
		$T_J = 25 \ ^{\circ}C \ (per \ leg)$		
	I <sub>R2</sub>	@V <sub>R</sub> = 200V, Pulse,	6.0	mA
		$T_J = 125 \ ^{\circ}C$ (per leg)		
Max. Junction Capacitance	CT	@V <sub>R</sub> = 5 V, T <sub>C</sub> = 25 °C	1800	pF
		f <sub>SIG</sub> = 1 MHz,		
		$V_{SIG} = 50 \text{mV} \text{ (p-p)} \text{ (per leg)}$		

Due to the nature of the 200V Schottky devices, some degradation in t<sub>rr</sub> performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

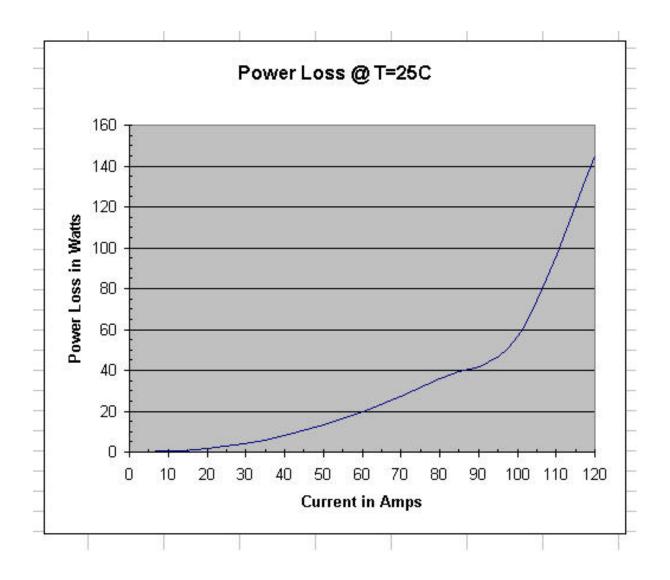
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#### Mechanical Dimensions: in inches / mm





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#### **TECHNICAL DATA**

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